

PDV-P8101

Light Dependent Resistor (LDR) CdS Photocell

The PDV-P8101 are (CdS), Photoconductive photocells designed to sense light from 400 to 700 nm. These light dependent resistors are available in a wide range of resistance values. They're packaged in a two leaded plastic-coated ceramic header.

Advanced Photonix's CdS Photocells are photoresistor cells for visible light measurement designed to sense light from 400 to 700 nm. Their resistance decreases as the light level increases with efficiency characteristics similar to the human eye. These Light Dependent Resistors (LDR) are available in a wide range of resistance values. They are available in a two leaded plastic-coated ceramic header or hermetically sealed TO metal can.

Applications

| Camera Exposure | |
|----------------------|--|
| Shutter Controls | |
| Night Light Controls | |
| Audio Compressors | |
| Solar Street Lights | |
| Flame Detection | |

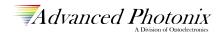
Features

| Visible Light Response |
|--|
| Sintered Construction |
| Two-leaded ceramic package |
| Available in a Hermetically sealed package |
| Available in a wide range of resistance values |











Absolute Maximum Ratings at T_A=23 °C

| Parameter | Symbol | Min | Max | Unit |
|-----------------------|---------------------|-----|------|--------|
| Voltage | $V_{_{\mathrm{R}}}$ | - | 150 | V |
| Power Dissipation | - | - | 100 | mW/ °C |
| Operating Temperature | T _{OP} | -30 | +75 | °C |
| Storage Temperature | T _{stg} | - | +260 | °C |

Typical Electro-Optical Specifications at T_A=23 °C

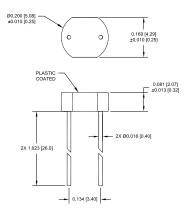
| Parameter | Test Conditions | Symbol | Min | Тур | Max | Unit |
|------------------------|---|---------------------|------|------|-----|-------|
| Dark Resistance | After 10 sec. @10Lux @2856°K | $R_{_{\mathrm{D}}}$ | 0.15 | - | - | ΜΩ |
| Illuminated Resistance | 10 Lux @ 2856°K | R _{IL} | 4 | - | 11 | ΚΩ |
| Sensitivity | Log (R100) - Log (R10)** Log (E100) - Log (E10) *** | S | - | 0.65 | - | Ω/Lux |
| Spectral Peak | - | λ_p | - | 520 | - | nm |
| Rise Time | 10Lux @ 2856°K | T _R | - | 60 | - | ms |
| Fall Time | After 10Lux @ 2856°K | T _F | - | 25 | - | ms |

^{**}R100, R10: cell resistances at 100 Lux and 10 Lux at 2856 K respectively.
***E100, E10: luminances at 100 Lux and 10 Lux 2856 K respectively.

E100, E10. Idillinances at 100 Edx and 10 Edx 2000 K Tespectiver

Mechanical Specifications

Units are in inches [mm]



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Care and handling instructions

Your optoelectronic components are packaged and shipped in opaque, padded containers to avoid ambient light exposure and damage due to shock from dropping or jarring.

Care must be taken to avoid exposure to high ambient light levels, particularly from tungsten sources or sunlight.

- These components can be rendered inoperable
 if dropped or sharply jarred. The wire bonds are
 delicate and can become separated from the
 bonding pads when the component is dropped or
 otherwise receives a sharp physical blow.
- Most windows on photodiodes are either silicon or quartz. They should be cleaned with isopropyl alcohol and a soft (optical grade) pad.
- Photodiode exposure to extreme high or low storage temperatures can affect the subsequent performance. Maintain a non-condensing environment for optimum performance and lifetime.
- All devices are considered ESD sensitive.
 The photodiodes are shipped in ESD protective packaging. When unpacking and using these products, anti-ESD precautions should be observed.
- Photodiode packages and/or operation may be impaired if exposed to CHLOROETHENE, THINNER, ACETONE, TRICHLOROETHYLENE or any harsh chemicals.

Legal Disclaimer

Information in this data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

- Optoelectronic components in plastic packages should be given special care. Clear plastic packages are more sensitive to environmental stress than those of black plastic. Storing devices in high humidity can present problems when soldering. Since the rapid heating during soldering stresses the wire bonds and can cause wire to bonding pad separation, it is recommended that devices in plastic packages to be baked for 24 hours at 85°C.
- The leads on the photodiode SHOULD NOT BE FORMED. If your application requires lead spacing modification, please contact Advanced Photonix Applications group at Techsupport@advancedphotonix.com before forming a product's leads. Product warranties could be voided.
- Most devices are provided with wire or pin leads for installation in circuit boards or sockets. Observe the soldering temperatures and conditions specified below:
 - Soldering Iron: Soldering 30 W or less
 - Temperature at tip of iron 300°C or lower.
 - Dip Soldering: Bath Temperature: 260±5°C.
 - Immersion Time: within 5 Sec.
 - Soldering Time: within 3 Sec.
 - Vapor Phase Soldering, Reflow Soldering: DO NOT USE



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